DATA SHEET

NEC

MOS FIELD EFFECT TRANSISTOR
2SJ327,327-Z

SWITCHING
P-CHANNEL POWER MOS FET

DESCRIPTION

The 2SJ327 is P-channel MOS Field Effect Transistor designed for solenoid, motor and lamp driver.

FEATURES

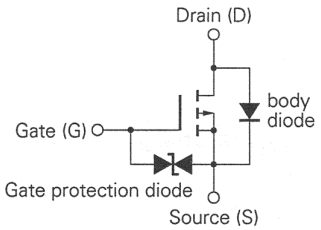
- Low On-state Resistance
  $R_{DS(on)}$ = 0.13 Ω TYP. (V_{GS} = –10 V, I_D = –2.0 A)
  $R_{DS(on)}$ = 0.21 Ω TYP. (V_{GS} = –4 V, I_D = –1.6 A)
- Low C_{iss}: C_{iss} = 750 pF TYP.
- Built-in G-S Gate Protection Diode

ABSOLUTE MAXIMUM RATINGS (T_A = 25°C)

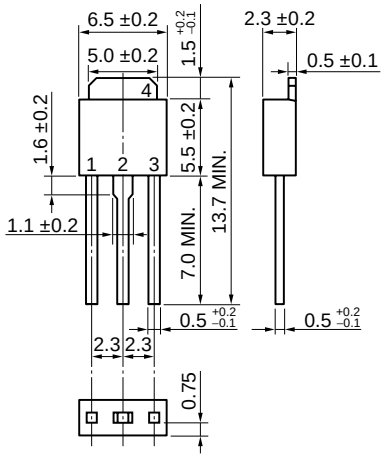
Drain to Source Voltage	V_{DSS}	–60	V
Gate to Source Voltage (AC)	$V_{GSS(AC)}$	∓20	V
Gate to Source Voltage (DC)	$V_{GSS(DC)}$	–20, +10	V
Drain Current (DC)	$I_{D(DC)}$	∓4.0	A
Drain Current (pulse) Note	$I_{D(pulse)}$	∓16	A
Total Power Dissipation (T_C = 25°C)	P_{T1}	20	W
Total Power Dissipation (T_A = 25°C)	P_{T2}	1.0	W
Channel Temperature	T_{ch}	150	°C
Storage Temperature	T_{stg}	–55 to +150	°C

Note PW ≤ 10 μs, Duty Cycle ≤ 1%

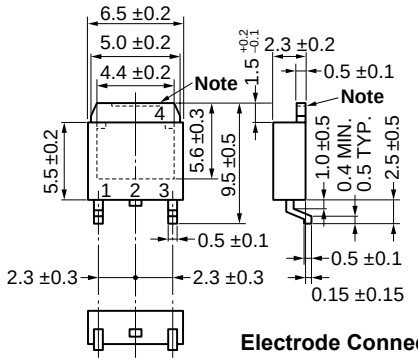
EQUIVALENT CIRCUIT



PACKAGE DRAWINGS (Unit: mm)



<R> TO-251 (MP-3)



TO-252 (MP-3Z)

Electrode Connection
1. Gate
2. Drain
3. Source
4. Drain Fin

Note The depth of notch at the top of the fin is from 0 to 0.2 mm.

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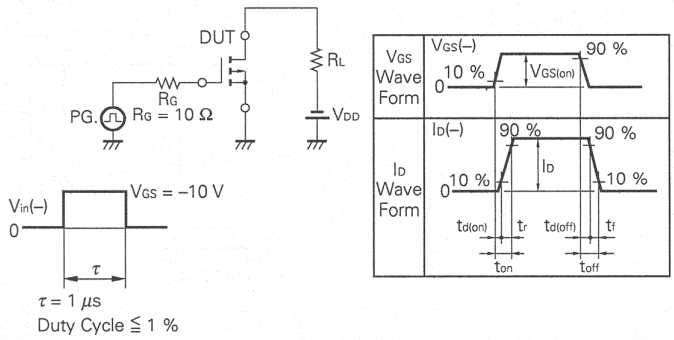
The mark <R> shows major revised points.
The revised points can be easily searched by copying an "<R>" in the PDF file and specifying it in the "Find what:" field.

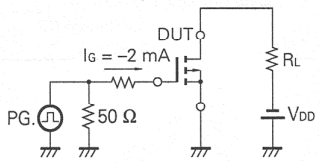
ELECTRICAL CHARACTERISTICS (T_a = 25 °C)

CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS
Drain to Source On-state Resistance	$R_{DS(on)}$		0.13	0.17	Ω	V_{GS} = –10 V, I_D = –2.0 A
Drain to Source On-state Resistance	$R_{DS(on)}$		0.21	0.34	Ω	V_{GS} = –4 V, I_D = –1.6 A
Gate to Source Cutoff Voltage	$V_{GS(off)}$	–1.0	–1.5	–2.0	V	V_{DS} = –10 V, I_D = –1 mA
Forward Transfer Admittance	$\|y_{fs}\|$	3.0	3.8		S	V_{DS} = –10 V, I_D = –2.0 A
Drain Leakage Current	I_{DSS}			–10	μA	V_{DS} = –60 V, V_{GS} = 0
Gate to Source Leakage Current	I_{GSS}			∓10	μA	V_{GS} = ∓16 V, V_{DS} = 0
Input Capacitance	C_{iss}		750		pF	V_{DS} = –10 V V_{GS} = 0 f = 1 MHz
Output Capacitance	C_{oss}		410		pF	
Reverse Transfer Capacitance	C_{rss}		165		pF	
Turn-On Delay Time	$t_{d(on)}$		10		ns	$V_{GS(on)}$ = –10 V V_{DD} = –30 V I_D = –2.0 A, R_G = 10 Ω R_L = 15 Ω
Rise Time	t_r		35		ns	
Turn-Off Delay Time	$t_{d(off)}$		85		ns	
Fall Time	t_f		45		ns	
Total Gate Charge	Q_G		27		nC	V_{GS} = –10 V I_D = –4.0 A V_{DD} = –48 V
Gate to Source Charge	Q_{GS}		2		nC	
Gate to Drain Charge	Q_{GD}		11		nC	
Body Diode Forward Voltage	V_F		0.9		V	I_F = 4.0 A, V_{GS} = 0
Reverse Recovery Time	t_{rr}		85		ns	I_F = 4.0 A, V_{GS} = 0 di/dt = 50 A/μs
Reverse Recovery Charge	Q_{rr}		130		nC	

Test Circuit 1: Switching Time

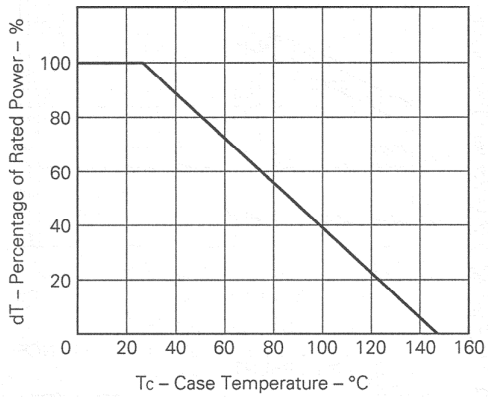


Test Circuit 2: Gate Charge

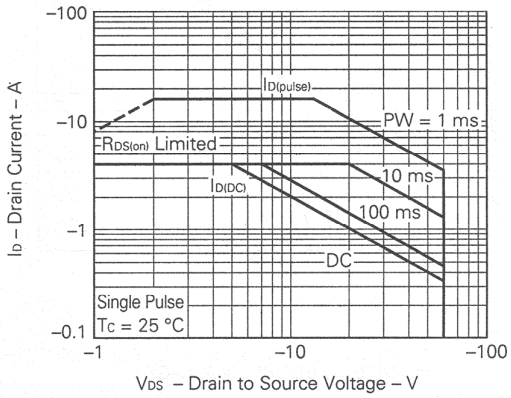


ELECTRICAL CHARACTERISTICS (T_a = 25 °C)

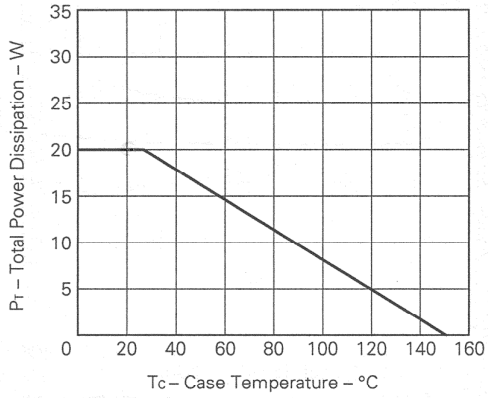
DERATING FACTOR OF FORWARD BIAS SAFE OPERATING AREA



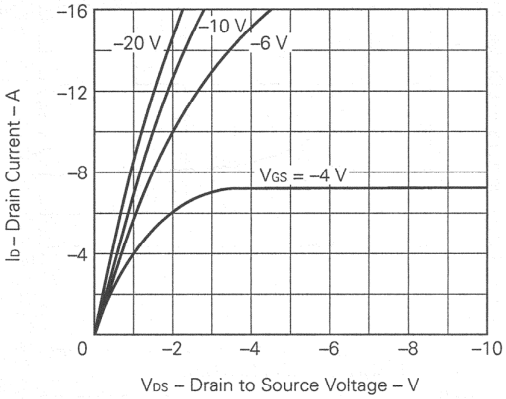
FORWARD BIAS SAFE OPERATING AREA



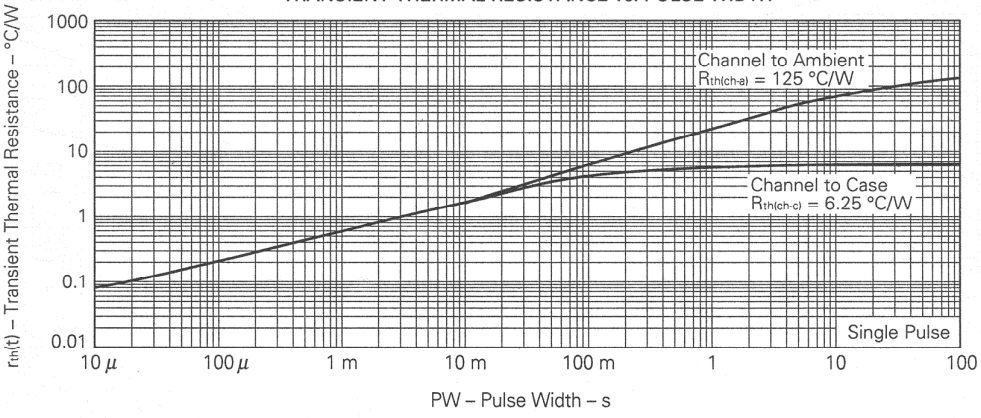
TOTAL POWER DISSIPATION vs. CASE TEMPERATURE



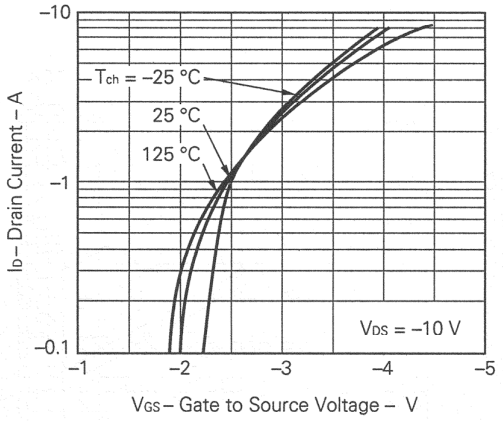
DRAIN CURRENT vs. DRAIN TO SOURCE VOLTAGE



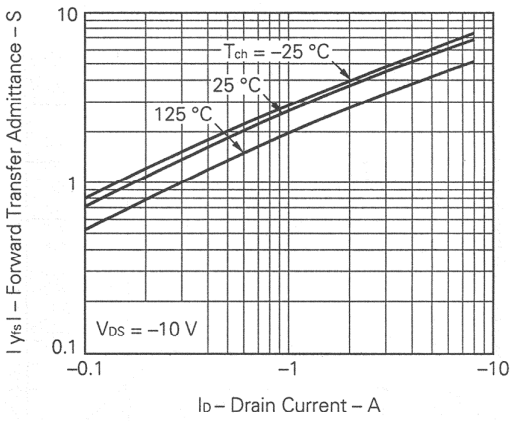
TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH



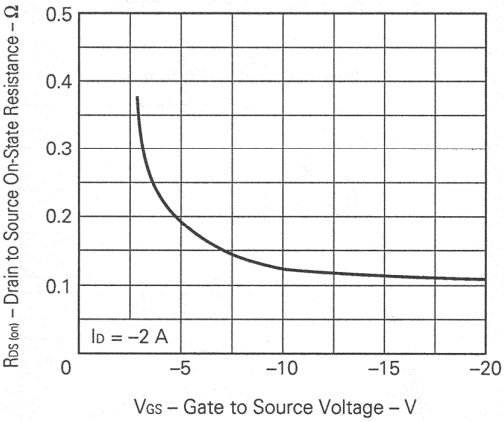
TRANSFER CHARACTERISTICS



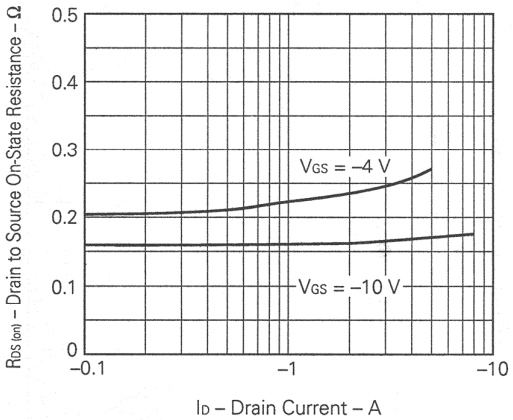
FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT



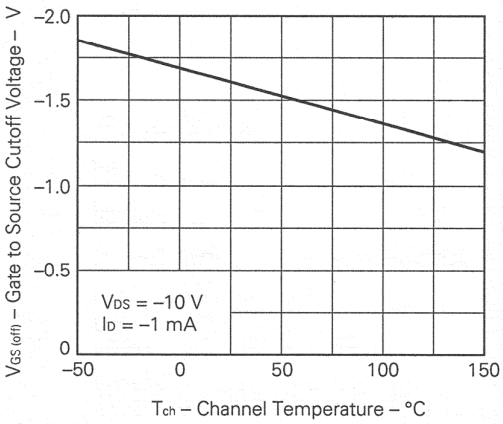
DRAIN TO SOURCE ON-STATE RESISTANCE vs. GATE TO SOURCE VOLTAGE



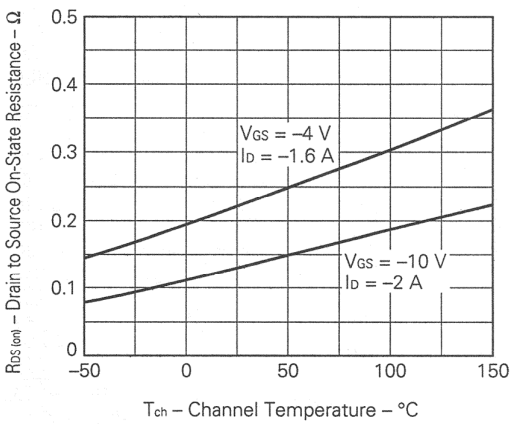
DRAIN TO SOURCE ON-STATE RESISTANCE vs. DRAIN CURRENT



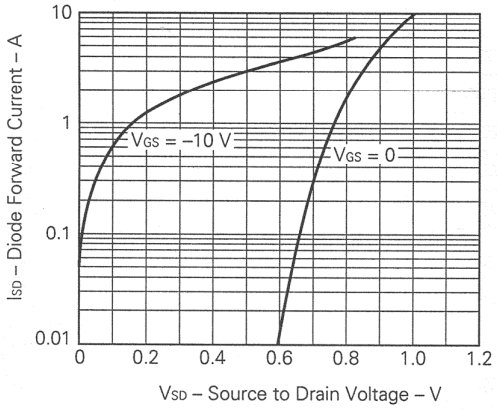
GATE TO SOURCE CUTOFF VOLTAGE vs. CHANNEL TEMPERATURE



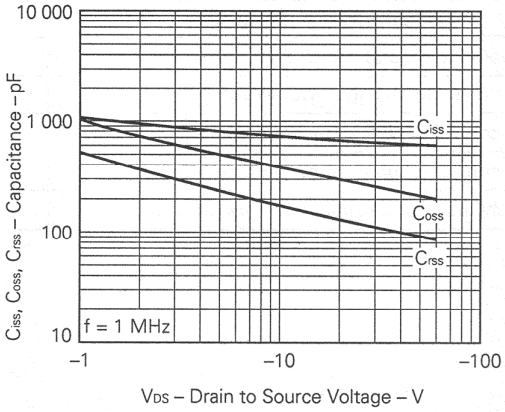
DRAIN TO SOURCE ON-STATE RESISTANCE vs. CHANNEL TEMPERATURE



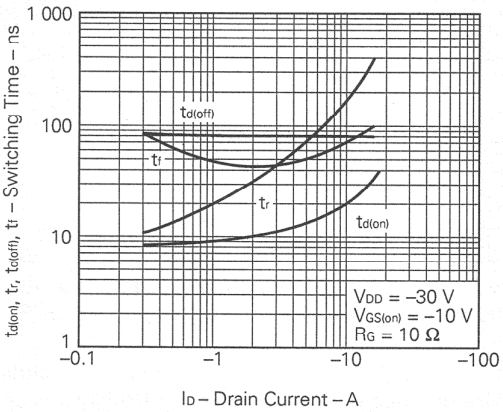
SOURCE TO DRAIN DIODE FORWARD VOLTAGE



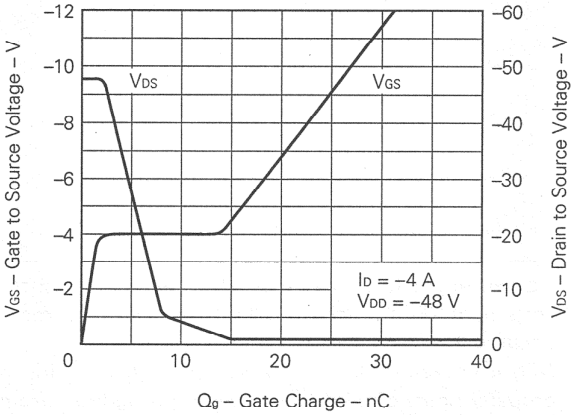
CAPACITANCE vs. DRAIN TO SOURCE VOLTAGE



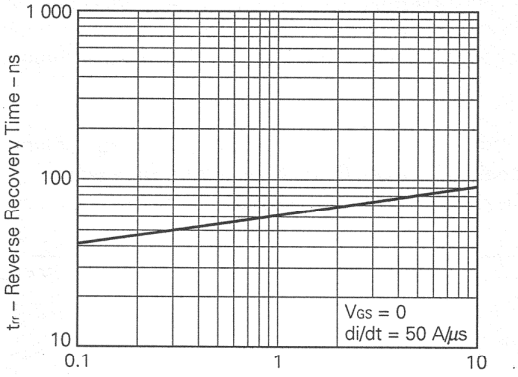
SWITCHING CHARACTERISTICS



DYNAMIC INPUT/OUTPUT CHARACTERISTICS



REVERSE RECOVERY TIME vs. REVERSE DRAIN CURRENT



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